TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

2SA1893

Strobe Flash Applications Audio Power Amplifier Applications

• $h_{FE(1)} = 100 \text{ to } 320 \text{ (V}_{CE} = -2 \text{ V}, I_{C} = -0.5 \text{ A)}$

• $h_{FE(2)} = 70 \text{ (min) (V}_{CE} = -2 \text{ V, I}_{C} = -4 \text{ A})$

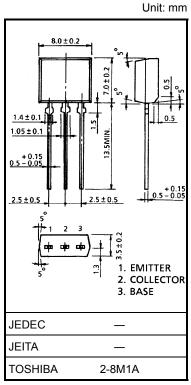
• Low saturation voltage: $V_{CE (sat)} = -1.0 \text{ V (max)}$

 $(I_C = -4 \text{ V}, I_B = -0.1 \text{ A})$

• High-power dissipation: PC = 1.3 W

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	-35	V	
Collector-emitter voltage		V _{CEO}	-20	V	
Emitter-base voltage		V _{EBO}	-8	٧	
Collector current	DC	Ic	-5	А	
	Pulsed (Note 1)	I _{CP}	-8		
Base current		ΙΒ	-0.5	Α	
Collector power dissipation		PC	1.3	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



Weight: 0.55 g (typ.)

Note 1: Conditions: Pulse width = 10 ms (max), duty cycle = 30% (max)

Note 2: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

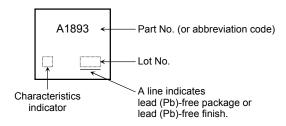
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

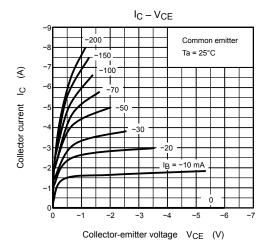
Electrical Characteristics (Ta = 25°C)

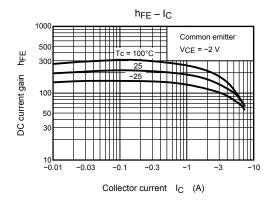
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = -35 \text{ V}, I_{E} = 0$	_	_	-100	nA
Emitter cut-off current	I _{EBO}	V _{EB} = -8 V, I _C = 0	_	_	-100	nA
Collector-emitter breakdown voltage	V (BR) CEO	$I_C = -10 \text{ mA}, I_B = 0$	-20	-		٧
DC current gain	h _{FE (1)} (Note 3)	V _{CE} = -2 V, I _C = -0.5 A	100	_	320	
	h _{FE (2)}	V _{CE} = -2 V, I _C = -4 A	70	_	_	
Collector-emitter saturation voltage	V _{CE (sat)}	I _C = -4 A, I _B = -0.1 A	_	_	-1.0	V
Base-emitter voltage	V_{BE}	V _{CE} = -2 V, I _C = -4 A	_	_	-1.5	V
Transition frequency	f _T	V _{CE} = -2 V, I _C = -0.5 A	_	170	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = -10 V, I _E = 0, f = 1 MHz	_	62	_	pF

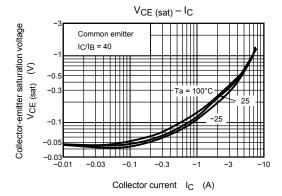
Note 3: $h_{FE(1)}$ classification O: 100 to 200, Y: 160 to 320

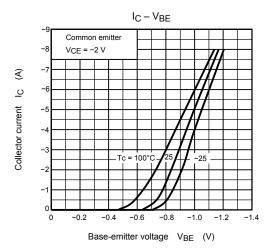
Marking



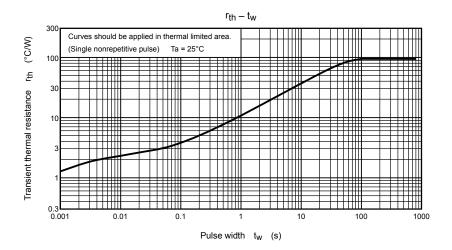


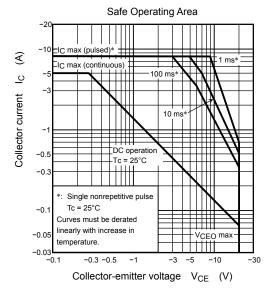


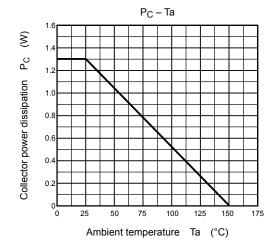




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